

BIPOLAR ANALOG INTEGRATED CIRCUITS

μ PC2745TB, μ PC2746TB

3 V, SUPER MINIMOLD SILICON MMIC WIDEBAND AMPLIFIER FOR MOBILE COMMUNICATIONS

DESCRIPTION

The μ PC2745TB and μ PC2746TB are silicon monolithic integrated circuits designed as buffer amplifier for mobile communications. These ICs are packaged in super minimold package which is smaller than conventional minimold.

The μ PC2745TB and μ PC2746TB have each compatible pin connections and performance to μ PC2745T/ μ PC2746T of conventional minimold version. So, in the case of reducing your system size, μ PC2745TB/ μ PC2746TB are suitable to replace from μ PC2745T/ μ PC2746T.

These ICs are manufactured using NEC's 20 GHz fr NESAT™III silicon bipolar process. This process uses silicon nitride passivation film and gold electrodes. These materials can protect chip surface from external pollution and prevent corrosion/migration. Thus, these IC have excellent performance, uniformity and reliability.

FEATURES

- High-density surface mounting : 6 pin super minimold package
- Supply voltage : Recommended $V_{CC} = 2.7$ to 3.3 V
Circuit operation $V_{CC} = 1.8$ to 3.3 V
- Wideband response : $f_u = 2.7$ GHz_{TYP.} @ μ PC2745TB
 $f_u = 1.5$ GHz_{TYP.} @ μ PC2746TB
- High isolation : ISL = 38 dB_{TYP.} @ μ PC2745TB
ISL = 45 dB_{TYP.} @ μ PC2746TB

APPLICATION

- 1.5 GHz to 2.5 GHz communication system (PHS, wireless LAN; etc.): μ PC2745TB
- 800 MHz to 900 MHz cellular telephone (CT2, GSM, etc.) : μ PC2746TB

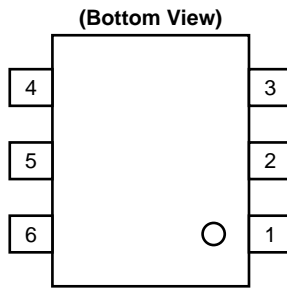
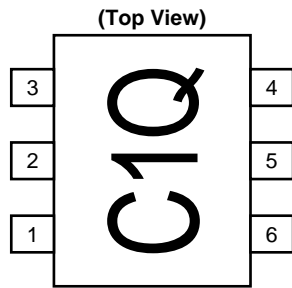
ORDERING INFORMATION

| PART NUMBER | PACKAGE | MARKING | SUPPLYING FORM | f_u |
|-------------------|-------------|---------|---|-------------------------|
| μ PC2745TB-E3 | 6 pin super | C1Q | Embossed tape 8 mm wide. 1, 2, 3 pins face to perforation side of the tape. Qty 3 kp/reel. | 2.7 GHz _{TYP.} |
| μ PC2746TB-E3 | minimold | C1R | | 1.5 GHz _{TYP.} |

Remarks To order evaluation samples, please contact your local NEC sales office.
(Part number: μ PC2745TB, μ PC2746TB)

Caution: Electro-static sensitive devices

PIN CONNECTIONS



| Pin NO. | Pin name |
|---------|-----------------|
| 1 | INPUT |
| 2 | GND |
| 3 | GND |
| 4 | OUTPUT |
| 5 | GND |
| 6 | V _{CC} |

Marking is an example of μ PC2745TB

PRODUCT LINE-UP OF μ PC2745, μ PC2746 ($T_A = +25\text{ }^\circ\text{C}$, $V_{CC} = 3.0\text{ V}$, $Z_L = Z_s = 50\ \Omega$)

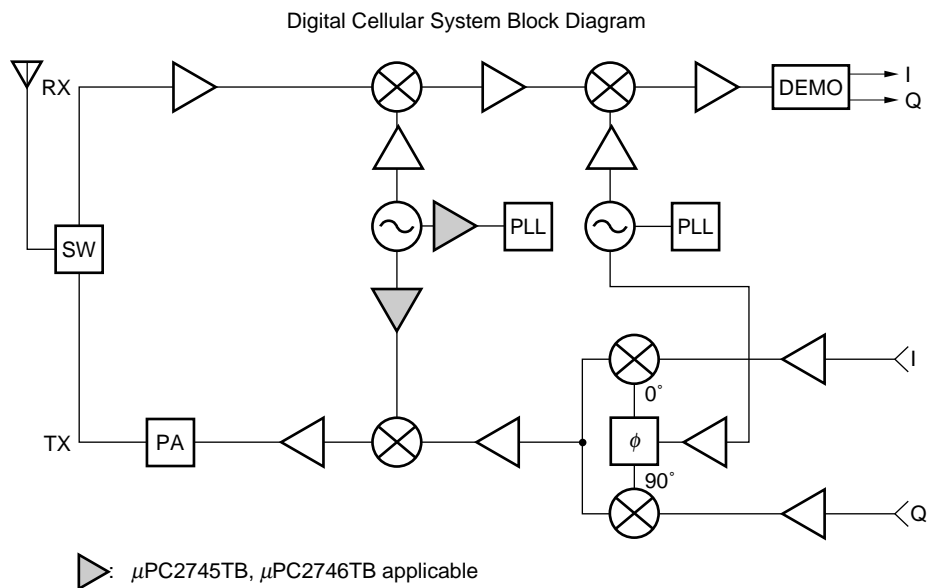
| PART NO. | f_u (GHz) | $P_{O(sat)}$ (dBm) | G_P (dB) | NF (dB) | I_{CC} (mA) | PACKAGE | MARKING |
|----------------|-------------|--------------------|------------|---------|---------------|----------------------|---------|
| μ PC2745T | 2.7 | -1 | 12 | 6.0 | 7.5 | 6 pin minimold | C1Q |
| μ PC2745TB | | | | | | 6 pin super minimold | |
| μ PC2746T | 1.5 | 0 | 19 | 4.0 | 7.5 | 6 pin minimold | C1R |
| μ PC2746TB | | | | | | 6 pin super minimold | |

Remarks Typical performance. Please refer to ELECTRICAL CHARACTERISTICS in detail.

Notice The package size distinguish between minimold and super minimold.

SYSTEM APPLICATION EXAMPLE

Digital Cellular System Block Diagram



To know the associated products, please refer to each latest data sheet.

PIN EXPLANATION

| Pin NO. | Pin Name | Applied voltage V | Pin voltage V ^{Note} | Function and applications | Internal equivalent circuit |
|-------------|-----------------|-------------------|-------------------------------|--|-----------------------------|
| 1 | INPUT | — | 0.87 ----- 0.82 | Signal input pin. A internal matching circuit, configured with resistors, enables 50 Ω connection over a wide band. this pin must be coupled to signal source with capacitor for DC cut. | |
| 4 | OUTPUT | — | 1.95 ----- 2.54 | Signal output pin. A internal matching circuit, configured with resistors, enables 50 Ω connection over a wide band. This pin must be coupled to next stage with capacitor for DC cut. | |
| 6 | V _{CC} | 2.7 to 3.3 | — | Power supply pin. This pin should be externally equipped with bypass capacity to minimize ground impedance. | |
| 2 3 5 | GND | 0 | — | Ground pin. This pin should be connected to system ground with minimum inductance. Ground pattern on the board should be formed as wide as possible. All the ground pins must be connected together with wide ground pattern to decrease impedance difference. | |

Note Pin voltage is measured at V_{CC} = 3.0 V. Above: μPC2745TB, Below: μPC2746TB

ABSOLUTE MAXIMUM RATINGS

| PARAMETER | SYMBOL | CONDITION | RATINGS | UNIT |
|-------------------------------|------------------|--|-------------|------|
| Supply voltage | V _{CC} | T _A = +25 °C | 4.0 | V |
| Circuit current | I _{CC} | T _A = +25 °C | 16 | mA |
| Input power level | P _{in} | T _A = +25 °C | 0 | dBm |
| Total power dissipation | P _D | Mounted on double sided copper clad 50 × 50 × 1.6 mm epoxy glass PWB (T _A = +85 °C) | 200 | mW |
| Operating ambient temperature | T _A | | -40 to +85 | °C |
| Storage temperature | T _{STG} | | -55 to +150 | °C |

RECOMMENDED OPERATING CONDITIONS

| PARAMETER | SYMBOL | MIN. | TYP. | MAX. | UNIT | NOTICE |
|-------------------------------|-----------------|------|------|------|------|--------|
| Supply voltage | V _{CC} | 2.7 | 3.0 | 3.3 | V | |
| Operating ambient temperature | T _A | -40 | +25 | +85 | °C | |

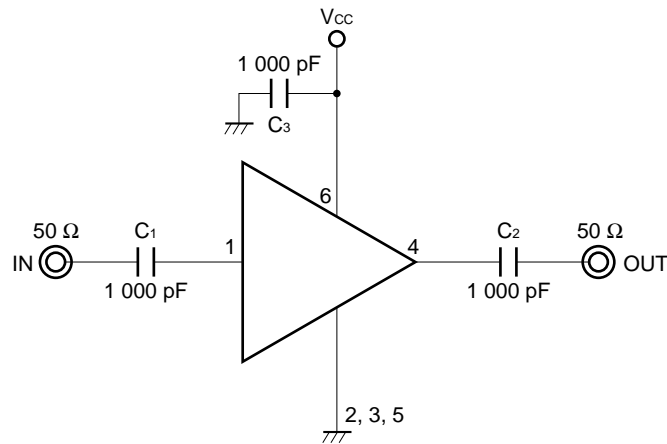
ELECTRICAL CHARACTERISTICS (T_A = + 25 °C, V_{CC} = 3.0 V, Z_L = Z_s = 50 Ω)

| PARAMETER | SYMBOL | TEST CONDITION | μ PC2745TB | | | μ PC2746TB | | | UNIT |
|---------------------------------|---------------------|--|----------------|------|------|----------------|------|------|------|
| | | | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. | |
| Circuit current | I _{CC} | No signals | 5.0 | 7.5 | 10.0 | 5.0 | 7.5 | 10.0 | mA |
| Power Gain | G _P | f = 0.5 GHz | 9.0 | 12 | 14 | 16 | 19 | 21 | dB |
| Noise figure | NF | f = 0.5 GHz | — | 6 | 7.5 | — | 4.0 | 5.5 | dB |
| Upper limit operating frequency | f _u | 3 dB down below from gain at f = 100 MHz | 2.3 | 2.7 | — | 1.1 | 1.5 | — | GHz |
| Isolation | ISL | f = 0.5 GHz | 33 | 38 | — | 40 | 45 | — | dB |
| Input return loss | RL _{in} | f = 0.5 GHz | 8 | 11 | — | 10 | 13 | — | dB |
| Output return loss | RL _{out} | f = 0.5 GHz | 2.5 | 5.5 | — | 5.5 | 8.5 | — | dB |
| Maximum output level | P _{O(sat)} | f = 0.5 GHz, P _{in} = -6 dBm | -4 | -1 | — | -3 | 0 | — | dBm |

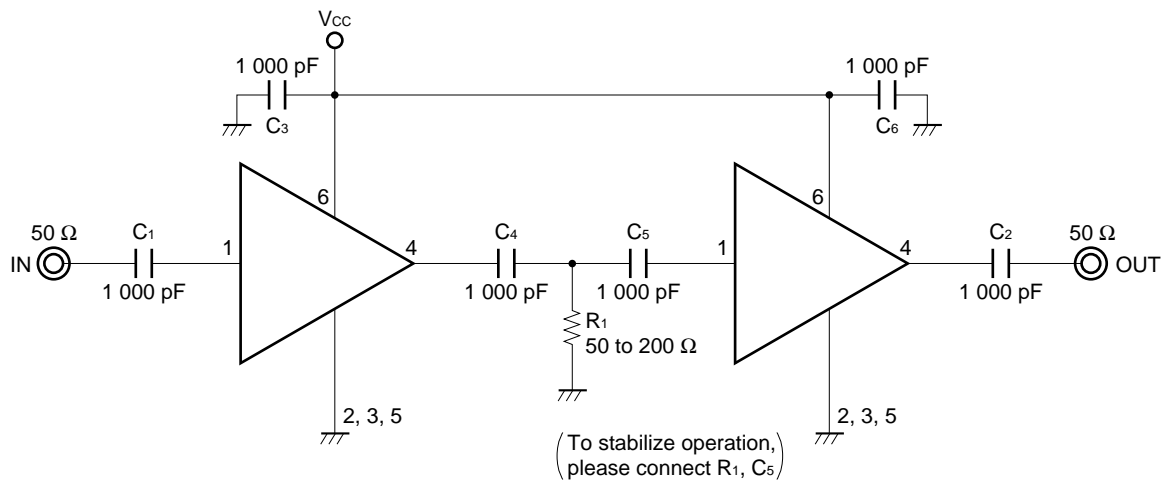
STANDARD CHARACTERISTICS FOR REFERENCE ($T_A = +25\text{ }^\circ\text{C}$, $V_{CC} = 3.0\text{ V}$, $Z_L = Z_S = 50\ \Omega$)

| PARAMETER | SYMBOL | TEST CONDITION | μ PC2745TB | μ PC2745B | UNIT |
|--------------------------------------|--------------|--|----------------|---------------|------|
| Circuit current | I_{CC} | $V_{CC} = 1.8\text{ V}$, No signals | 4.5 | 4.5 | mA |
| Power Gain | G_P | $V_{CC} = 3.0\text{ V}$, $f = 1\text{ GHz}$ | 12 | 18.5 | dB |
| | | $V_{CC} = 3.0\text{ V}$, $f = 2\text{ GHz}$ | 11 | — | |
| | | $V_{CC} = 1.8\text{ V}$, $f = 500\text{ MHz}$ | 7 | 14 | |
| Noise figure | NF | $V_{CC} = 3.0\text{ V}$, $f = 1\text{ GHz}$ | 5.5 | 4.2 | dB |
| | | $V_{CC} = 3.0\text{ V}$, $f = 2\text{ GHz}$ | 5.7 | — | |
| | | $V_{CC} = 1.8\text{ V}$, $f = 500\text{ MHz}$ | 8.0 | 5.0 | |
| Upper limit operating frequency | f_u | $V_{CC} = 1.8\text{ V}$, 3 dB down below from gain at $f = 100\text{ MHz}$ | 1.8 | 1.1 | GHz |
| Isolation | ISL | $V_{CC} = 3.0\text{ V}$, $f = 1\text{ GHz}$ | 33 | 38 | dB |
| | | $V_{CC} = 3.0\text{ V}$, $f = 2\text{ GHz}$ | 30 | — | |
| | | $V_{CC} = 1.8\text{ V}$, $f = 500\text{ MHz}$ | 35 | 37 | |
| Input return loss | RL_{in} | $V_{CC} = 3.0\text{ V}$, $f = 1\text{ GHz}$ | 13 | 10 | dB |
| | | $V_{CC} = 3.0\text{ V}$, $f = 2\text{ GHz}$ | 14 | — | |
| | | $V_{CC} = 1.8\text{ V}$, $f = 500\text{ MHz}$ | 6.5 | 10 | |
| Output return loss | RL_{out} | $V_{CC} = 3.0\text{ V}$, $f = 1\text{ GHz}$ | 6.5 | 8.5 | dB |
| | | $V_{CC} = 3.0\text{ V}$, $f = 2\text{ GHz}$ | 8.5 | — | |
| | | $V_{CC} = 1.8\text{ V}$, $f = 500\text{ MHz}$ | 6.0 | 9.5 | |
| Maximum output level | $P_{O(sat)}$ | $V_{CC} = 3.0\text{ V}$, $f = 1\text{ GHz}$, $P_{in} = -6\text{ dBm}$ | -2.5 | -1 | dBm |
| | | $V_{CC} = 3.0\text{ V}$, $f = 2\text{ GHz}$, $P_{in} = -6\text{ dBm}$ | -3.5 | — | |
| | | $V_{CC} = 1.8\text{ V}$, $f = 500\text{ MHz}$, $P_{in} = -10\text{ dBm}$ | -11 | -8 | |
| 3rd order intermodulation distortion | IM_3 | $V_{CC} = 3.0\text{ V}$, $P_{out} = -20\text{ dBm}$, $f_1 = 500\text{ MHz}$, $f_2 = 502\text{ MHz}$ | -54 | -51 | dBc |
| | | $V_{CC} = 3.0\text{ V}$, $P_{out} = -20\text{ dBm}$, $f_1 = 1\ 000\text{ MHz}$, $f_2 = 1\ 002\text{ MHz}$ | -50 | — | |
| | | $V_{CC} = 1.8\text{ V}$, $P_{out} = -20\text{ dBm}$, $f_1 = 500\text{ MHz}$, $f_2 = 502\text{ MHz}$ | -31 | -37 | |

TEST CIRCUIT



EXAMPLE OF APPLICATION CIRCUIT



The application circuits and their parameters are for references only and are not intended for use in actual design-in's.

Capacitors for Vcc, input and output pins

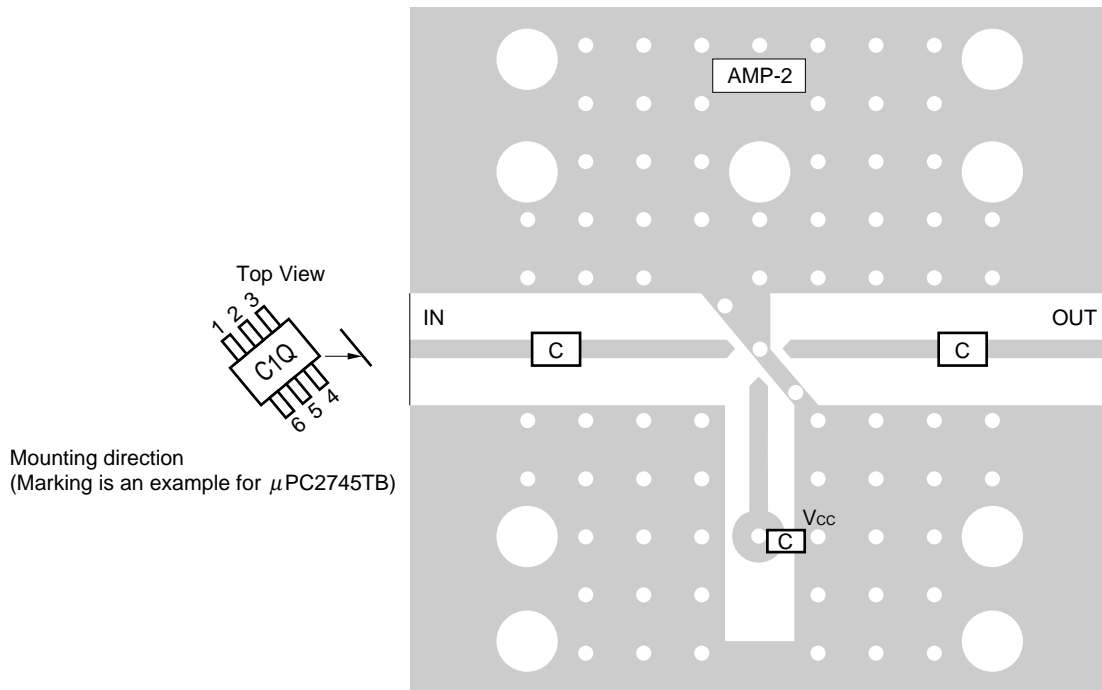
1 000 pF capacitors are recommendable as bypass capacitor for Vcc pin and coupling capacitors for input/output pins.

Bypass capacitor for Vcc pin is intended to minimize Vcc pin's ground impedance. Therefore, stable bias can be supplied against Vcc fluctuation.

Coupling capacitors for input/output pins are intended to minimize RF serial impedance and cut DC.

To get flat gain from 100 MHz up, 1 000 pF capacitors are assembled on the test circuit. [Actually, 1 000 pF capacitors give flat gain at least 10 MHz. In the case of under 10 MHz operation, increase the value of coupling capacitor such as 2 200 pF. Because the coupling capacitors are determined by the equation of $C = 1/(2 \pi fZs)$.]

Illustration of the test circuit assembled on evaluation board



Component List

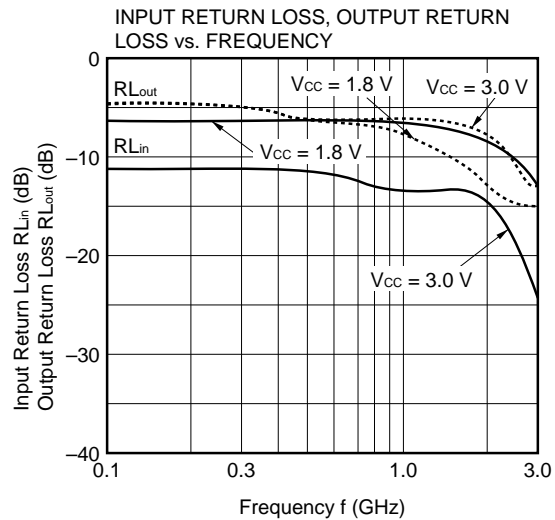
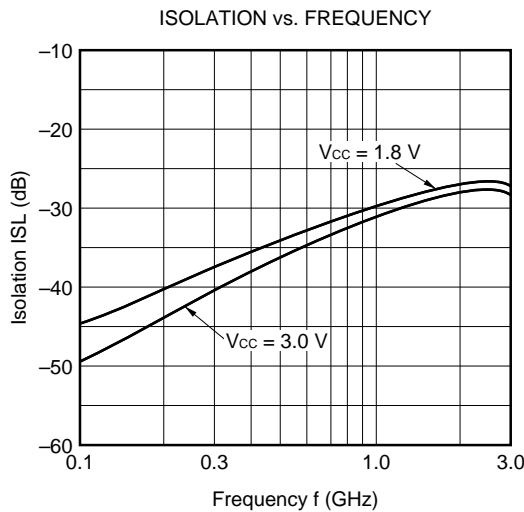
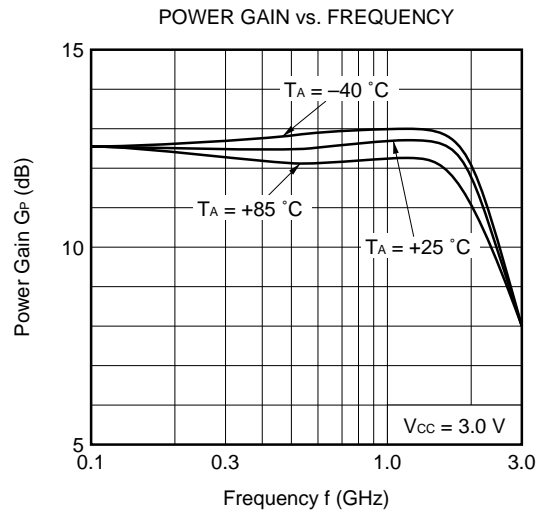
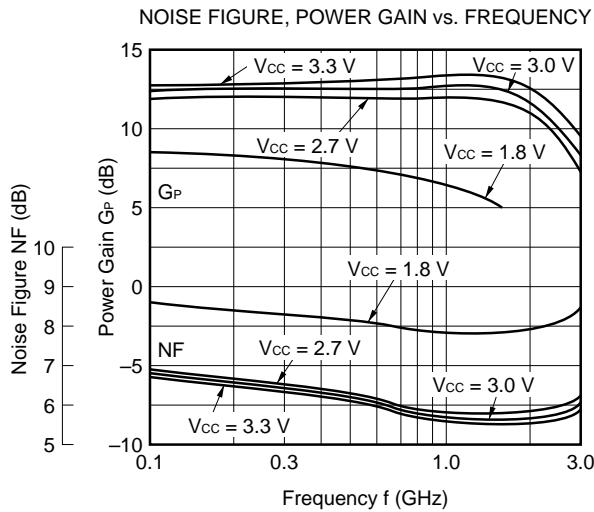
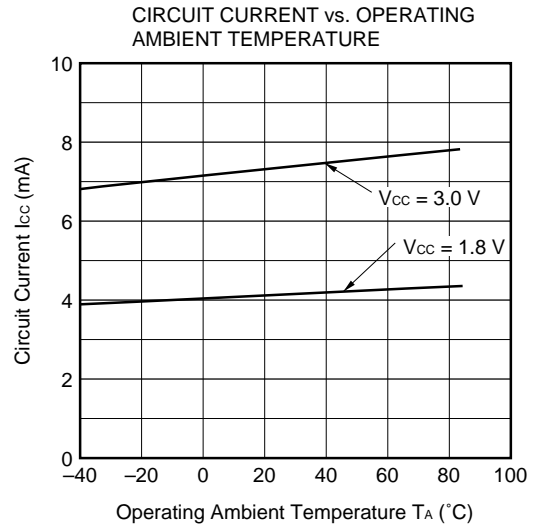
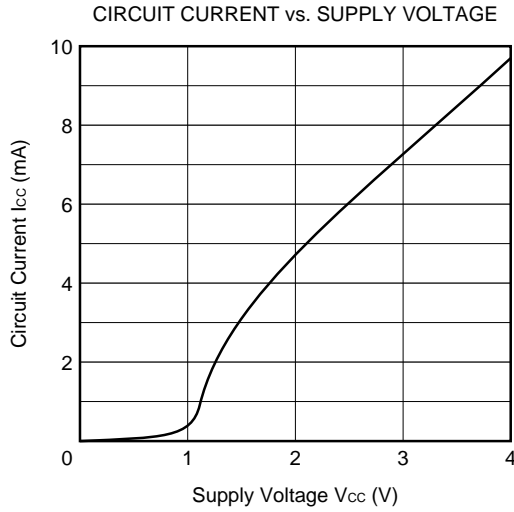
| | Value |
|---|----------|
| C | 1 000 pF |

Notes

1. 30 × 30 × 0.4 mm double sided copper clad polyimide board.
2. Back side: GND pattern
3. Solder plated on pattern
4. $\oplus\oplus\oplus$: Through holes

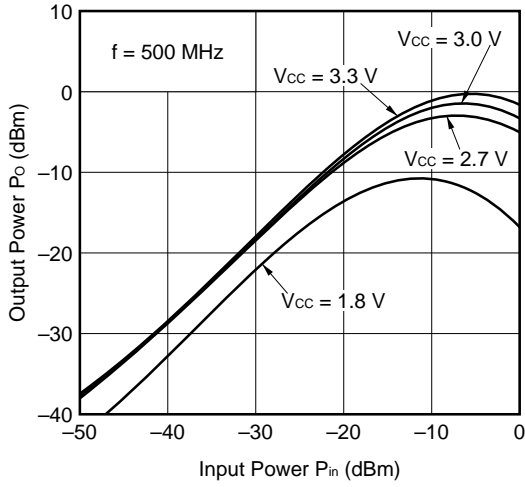
TYPICAL CHARACTERISTICS (Unless otherwise specified, $T_A = +25\text{ }^\circ\text{C}$)

— μ PC2745TB —

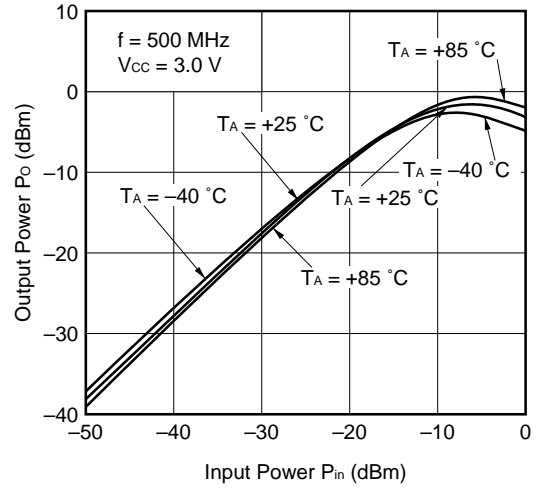


— μ PC2745TB —

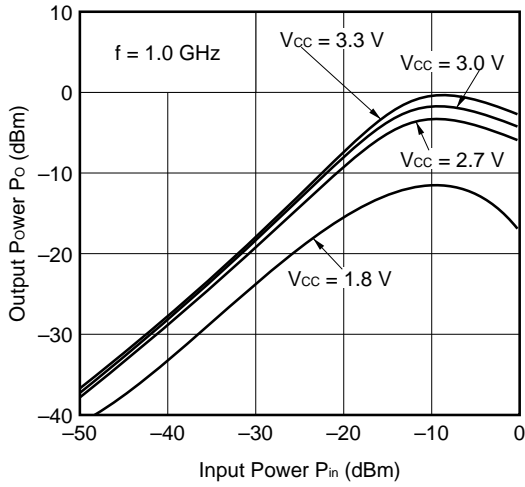
OUTPUT POWER vs. INPUT POWER



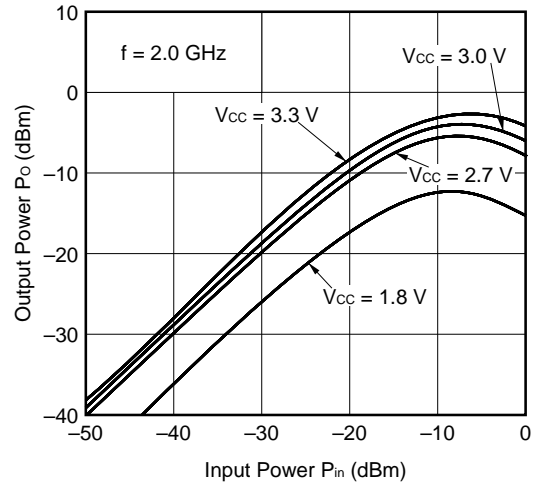
OUTPUT POWER vs. INPUT POWER



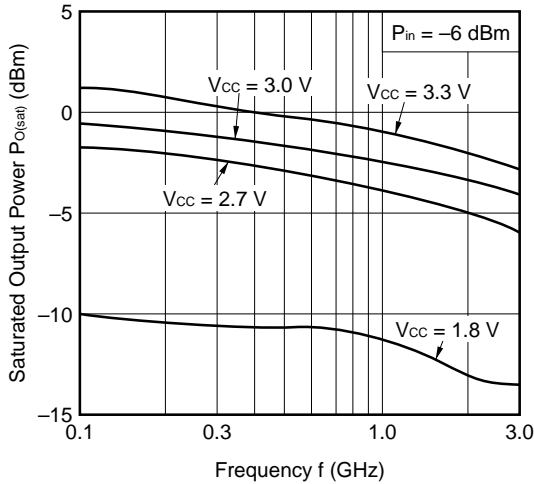
OUTPUT POWER vs. INPUT POWER



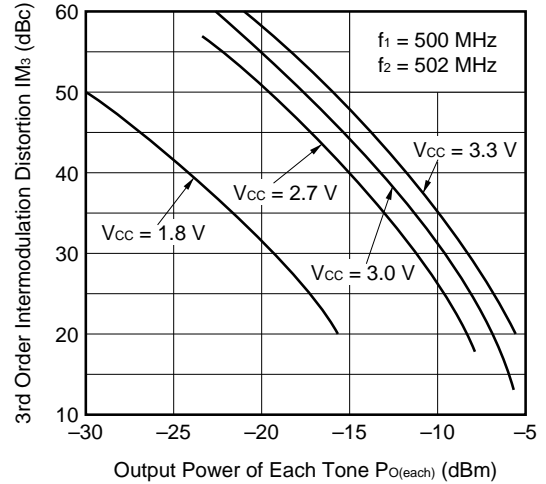
OUTPUT POWER vs. INPUT POWER



SATURATED OUTPUT POWER vs. FREQUENCY



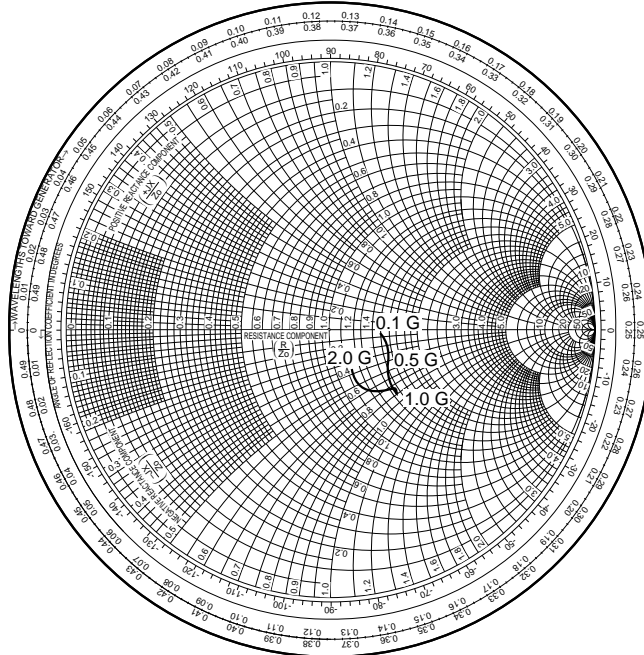
3RD ORDER INTERMODULATION DISTORTION vs. OUTPUT POWER OF EACH TONE



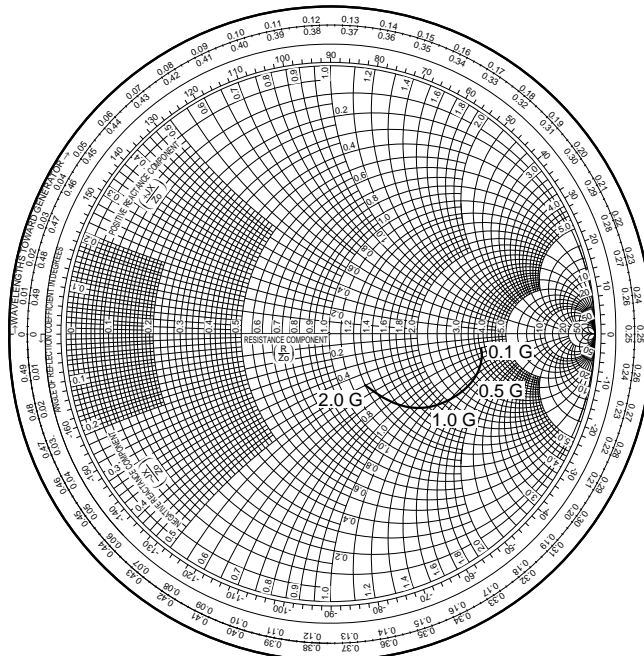
S Parameter ($V_{cc} = 3.0\text{ V}$)

— μ PC2745TB —

S₁₁-FREQUENCY



S₂₂-FREQUENCY



Typical S Parameter Values (T_A = +25 °C)

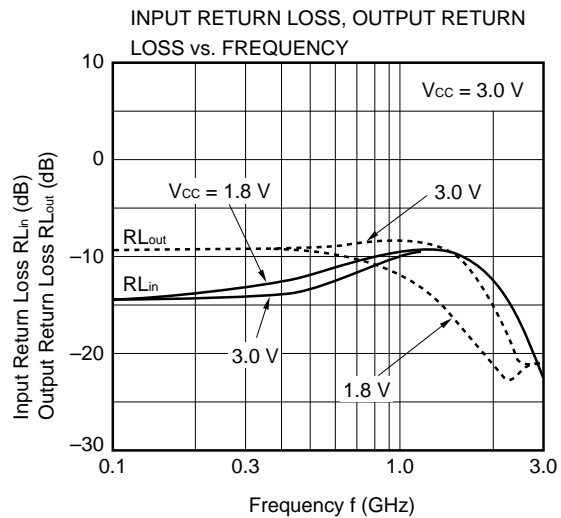
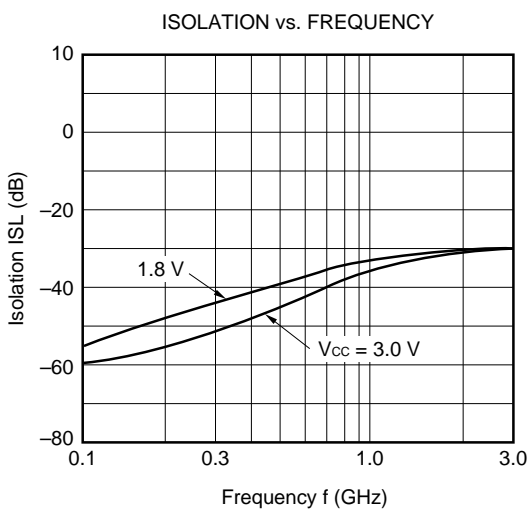
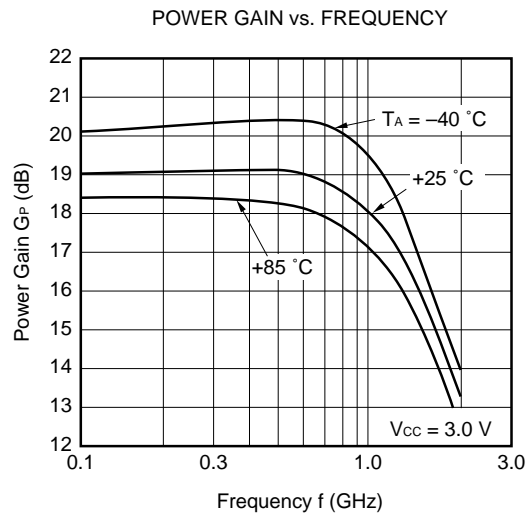
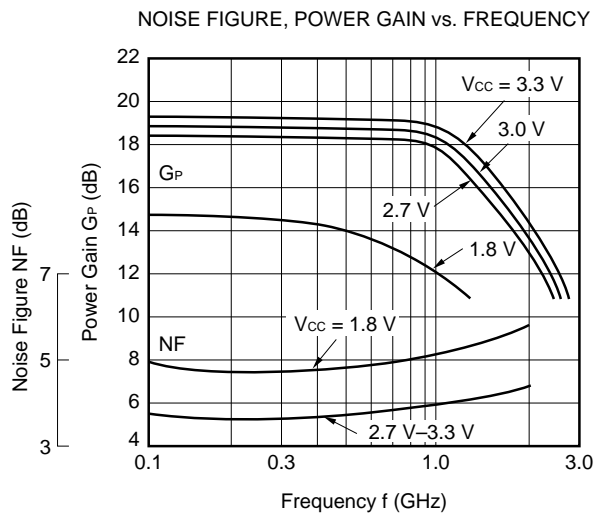
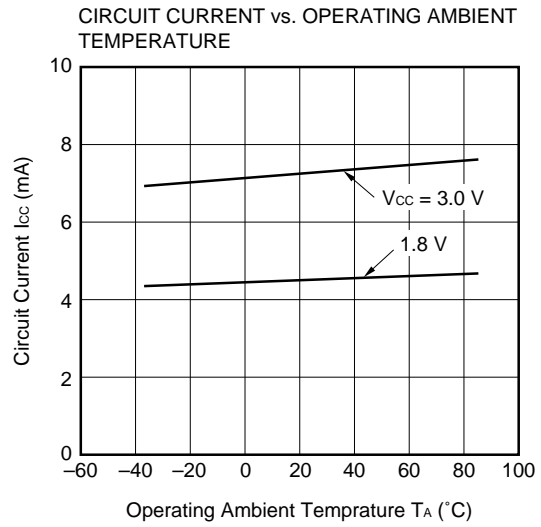
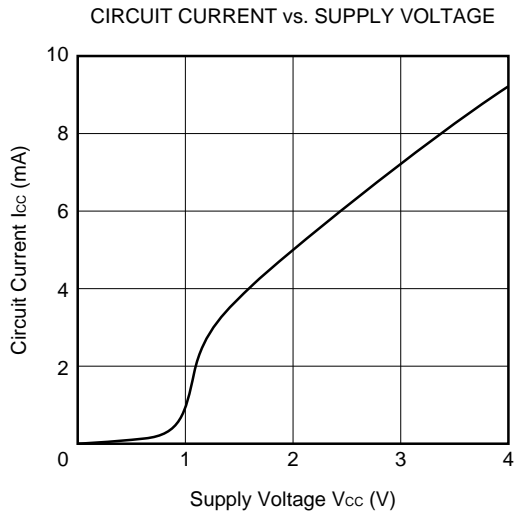
μPC2745TB

V_{CC} = 3.0 V, I_{CC} = 8.4 mA

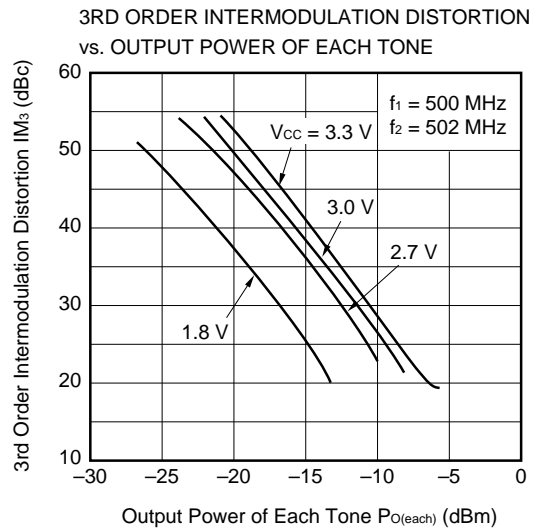
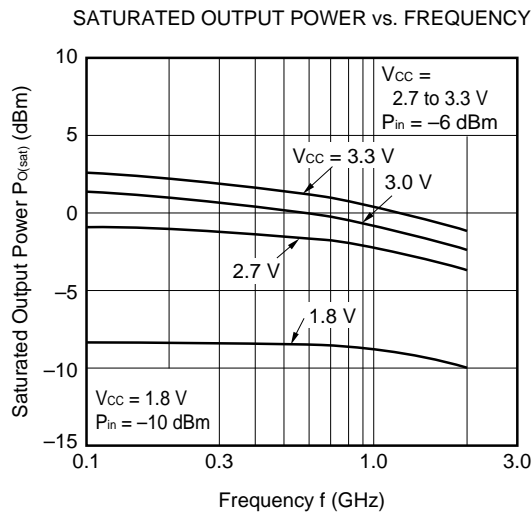
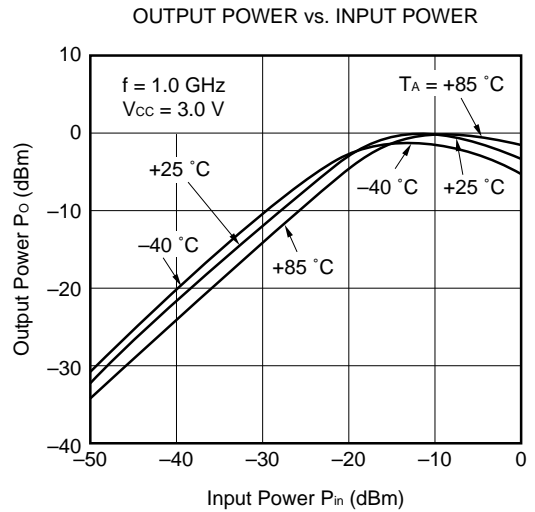
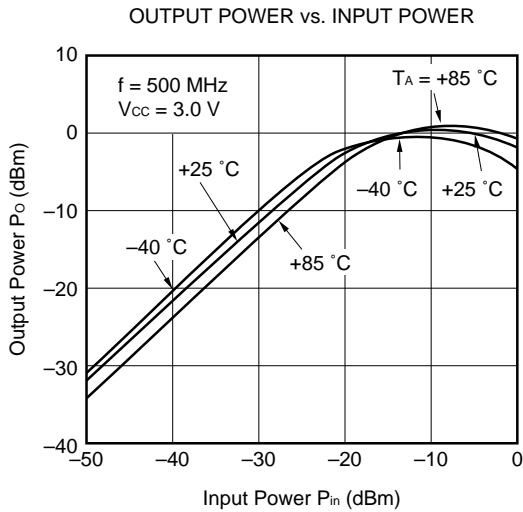
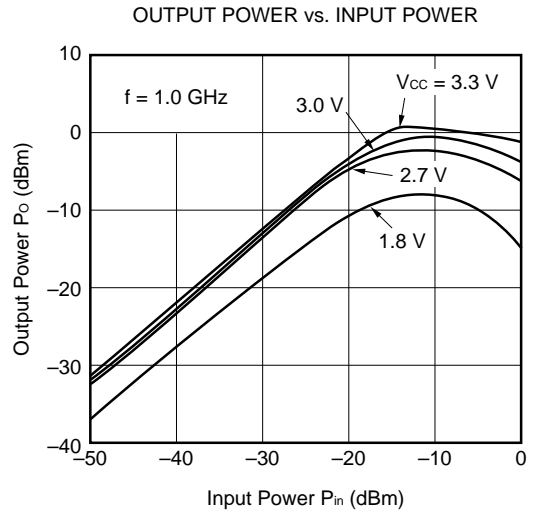
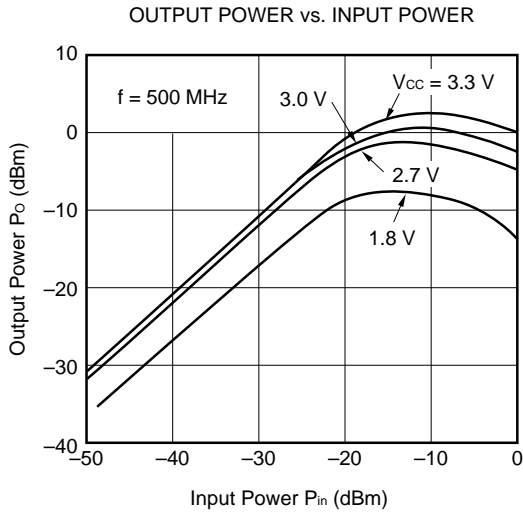
| FREQUENCY MHz | S11 | | S21 | | S12 | | S22 | | K |
|------------------|------|-------|-------|--------|------|--------|------|-------|-------|
| | MAG | ANG | MAG | ANG | MAG | ANG | MAG | ANG | |
| 100.0000 | .318 | -3.9 | 4.055 | -17.2 | .003 | 62.9 | .593 | -6.6 | 20.94 |
| 200.0000 | .325 | -5.9 | 4.030 | -35.5 | .006 | 54.2 | .584 | -12.1 | 11.68 |
| 300.0000 | .346 | -7.2 | 3.985 | -52.5 | .009 | 42.0 | .579 | -16.5 | 8.29 |
| 400.0000 | .341 | -8.9 | 3.916 | -70.7 | .012 | 29.4 | .562 | -20.6 | 6.26 |
| 500.0000 | .339 | -10.8 | 3.842 | -87.3 | .013 | 11.8 | .546 | -23.0 | 6.29 |
| 600.0000 | .326 | -13.9 | 3.775 | -104.7 | .015 | 1.6 | .527 | -26.2 | 5.50 |
| 700.0000 | .311 | -20.8 | 3.668 | -121.5 | .017 | -11.9 | .515 | -29.9 | 5.46 |
| 800.0000 | .312 | -25.8 | 3.594 | -138.1 | .018 | -24.2 | .511 | -32.4 | 5.36 |
| 900.0000 | .325 | -31.9 | 3.525 | -154.2 | .020 | -38.4 | .512 | -34.8 | 4.91 |
| 1000.0000 | .356 | -32.8 | 3.497 | -170.3 | .019 | -45.9 | .523 | -35.8 | 4.93 |
| 1100.0000 | .382 | -32.7 | 3.503 | 173.7 | .020 | -54.3 | .525 | -36.3 | 4.56 |
| 1200.0000 | .416 | -31.2 | 3.542 | 156.7 | .022 | -70.5 | .530 | -36.8 | 4.14 |
| 1300.0000 | .416 | -30.9 | 3.569 | 139.1 | .023 | -78.4 | .518 | -37.5 | 3.92 |
| 1400.0000 | .415 | -30.8 | 3.520 | 121.4 | .025 | -88.4 | .509 | -38.8 | 3.53 |
| 1500.0000 | .393 | -30.3 | 3.501 | 103.7 | .025 | -102.9 | .492 | -40.5 | 3.68 |
| 1600.0000 | .386 | -31.3 | 3.429 | 86.8 | .025 | -114.1 | .481 | -42.5 | 3.78 |
| 1700.0000 | .373 | -30.5 | 3.355 | 69.7 | .026 | -125.7 | .474 | -43.8 | 3.68 |
| 1800.0000 | .369 | -31.6 | 3.303 | 52.7 | .028 | -130.3 | .468 | -44.8 | 3.50 |
| 1900.0000 | .366 | -29.6 | 3.229 | 35.8 | .028 | -142.5 | .457 | -44.8 | 3.63 |
| 2000.0000 | .353 | -30.0 | 3.179 | 18.8 | .030 | -152.4 | .440 | -45.0 | 3.62 |
| 2100.0000 | .344 | -28.6 | 3.081 | 1.5 | .031 | -164.9 | .416 | -45.0 | 3.85 |
| 2200.0000 | .313 | -29.5 | 2.999 | -15.4 | .031 | -177.1 | .389 | -45.4 | 4.23 |
| 2300.0000 | .293 | -31.6 | 2.911 | -32.5 | .033 | 171.1 | .365 | -46.4 | 4.23 |
| 2400.0000 | .267 | -35.1 | 2.802 | -49.4 | .034 | 160.8 | .346 | -47.4 | 4.40 |
| 2500.0000 | .262 | -39.9 | 2.695 | -66.0 | .036 | 148.3 | .331 | -48.2 | 4.45 |
| 2600.0000 | .253 | -40.3 | 2.598 | -82.3 | .036 | 134.8 | .321 | -48.3 | 4.54 |
| 2700.0000 | .253 | -40.9 | 2.496 | -98.6 | .034 | 121.4 | .311 | -47.6 | 5.08 |
| 2800.0000 | .248 | -35.5 | 2.400 | -114.6 | .036 | 106.5 | .299 | -46.7 | 5.01 |
| 2900.0000 | .237 | -30.2 | 2.306 | -130.2 | .032 | 92.8 | .279 | -46.3 | 5.88 |
| 3000.0000 | .230 | -20.6 | 2.209 | -146.4 | .031 | 83.6 | .254 | -46.2 | 6.49 |

TYPICAL CHARACTERISTICS (Unless otherwise specified, $T_A = +25\text{ }^\circ\text{C}$)

— μ PC2746TB —



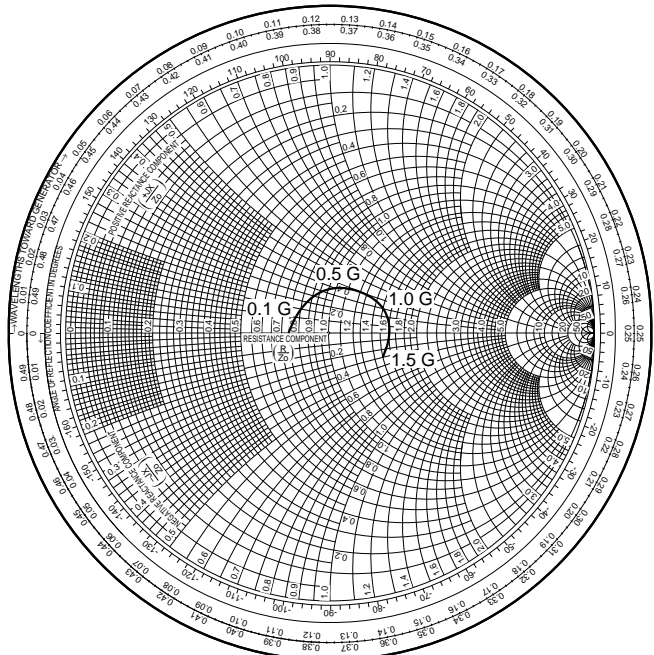
— μ PC2746TB —



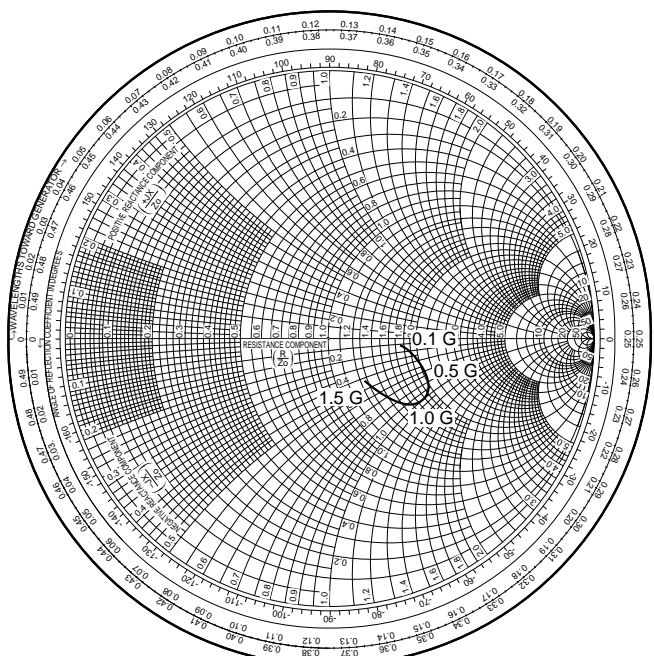
S Parameter ($V_{cc} = 3.0\text{ V}$)

— μ PC2746TB —

S₁₁-FREQUENCY



S₂₂-FREQUENCY



Typical S Parameter Values (T_A = +25 °C)

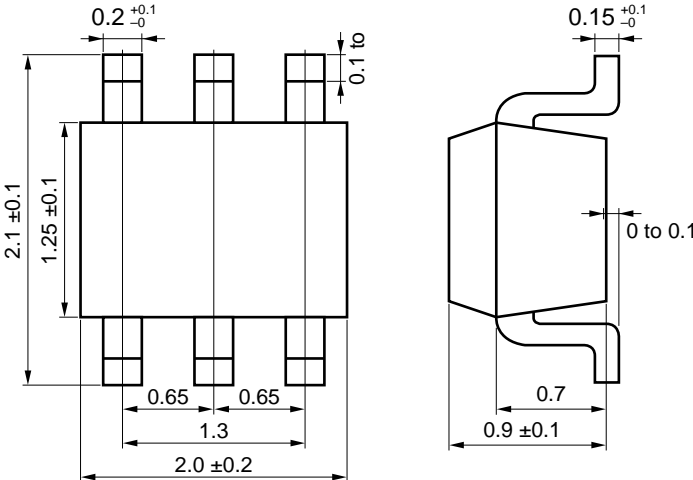
μPC2746TB

V_{CC} = 3.0 V, I_{CC} = 7.7 mA

| FREQUENCY MHz | S11 | | S21 | | S12 | | S22 | | K |
|------------------|------|-------|-------|--------|------|--------|------|-------|--------|
| | MAG | ANG | MAG | ANG | MAG | ANG | MAG | ANG | |
| 100.0000 | .146 | 165.0 | 6.443 | -19.4 | .001 | 77.0 | .403 | -5.3 | 108.63 |
| 200.0000 | .130 | 141.7 | 6.594 | -38.7 | .003 | 51.8 | .406 | -8.6 | 20.56 |
| 300.0000 | .117 | 117.9 | 6.623 | -58.1 | .004 | 47.7 | .418 | -11.0 | 16.33 |
| 400.0000 | .128 | 100.8 | 6.522 | -77.5 | .005 | 51.1 | .417 | -14.0 | 12.34 |
| 500.0000 | .139 | 90.8 | 6.613 | -96.9 | .008 | 33.1 | .424 | -16.2 | 8.14 |
| 600.0000 | .145 | 83.1 | 6.481 | -116.1 | .009 | 21.7 | .422 | -19.4 | 7.22 |
| 700.0000 | .135 | 77.0 | 6.424 | -135.1 | .010 | 14.7 | .426 | -23.8 | 6.52 |
| 800.0000 | .131 | 67.4 | 6.353 | -153.6 | .011 | -4 | .433 | -27.7 | 5.63 |
| 900.0000 | .119 | 49.3 | 6.234 | -172.1 | .014 | -10.5 | .442 | -32.1 | 4.80 |
| 1000.0000 | .142 | 30.4 | 6.137 | 169.6 | .015 | -24.2 | .455 | -34.7 | 4.44 |
| 1100.0000 | .170 | 18.0 | 5.992 | 151.1 | .016 | -28.7 | .455 | -37.5 | 4.02 |
| 1200.0000 | .219 | 10.6 | 5.972 | 133.3 | .019 | -48.0 | .453 | -39.7 | 3.49 |
| 1300.0000 | .245 | 7.4 | 5.867 | 115.1 | .019 | -63.4 | .433 | -42.7 | 3.40 |
| 1400.0000 | .268 | 3.1 | 5.679 | 97.0 | .022 | -72.2 | .409 | -45.5 | 3.16 |
| 1500.0000 | .270 | 1.5 | 5.582 | 79.1 | .021 | -86.9 | .375 | -48.3 | 3.38 |
| 1600.0000 | .268 | -3.9 | 5.380 | 61.8 | .022 | -99.6 | .349 | -49.9 | 3.36 |
| 1700.0000 | .258 | -7.8 | 5.122 | 44.5 | .024 | -110.7 | .318 | -50.0 | 3.42 |
| 1800.0000 | .251 | -14.3 | 4.880 | 27.9 | .024 | -122.9 | .294 | -49.2 | 3.67 |
| 1900.0000 | .249 | -16.7 | 4.634 | 11.7 | .025 | -135.3 | .268 | -45.4 | 3.73 |
| 2000.0000 | .240 | -20.5 | 4.475 | -4.4 | .026 | -146.0 | .248 | -40.5 | 3.91 |

PACKAGE DIMENSIONS

6 pin super minimold (unit : mm)



NOTES ON CORRECT USE

- (1) Observe precautions for handling because of electro-static sensitive devices.
- (2) Form a ground pattern as wide as possible to minimize ground impedance (to prevent undesired oscillation). All the ground pins must be connected together with wide ground pattern to decrease impedance difference.
- (3) The bypass capacitor should be attached to Vcc line.
- (4) The DC cut capacitor must be each attached to input and output pin.

RECOMMENDED SOLDERING CONDITIONS

This product should be soldered in the following recommended conditions. Other soldering methods and conditions than the recommended conditions are to be consulted with our sales representatives.

μPC2745TB, μPC2746TB

| Soldering method | Soldering conditions | Recommended condition symbol |
|---------------------|---|------------------------------|
| Infrared ray reflow | Package peak temperature : 235 °C, Hour : within 30 s. (more than 210 °C) Time : 3 times, Limited days : no.* | IR35-00-3 |
| VPS | Package peak temperature : 215 °C, Hour : within 40 s. (more than 200 °C) Time : 3 times, Limited days : no.* | VP15-00-3 |
| Wave soldering | Soldering tub temperature : less than 260 °C, Hour : within 10 s. Time : 1 times, Limited days : no.* | WS60-00-1 |
| Pin part heating | Pin area temperature : 300 °C, Hour : within 3 s/pin. Limited days : no.* | |

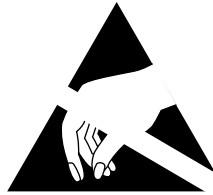
* It is the storage days after opening a dry pack, the storage conditions are 25 °C, less than 65 % RH.

Note 1. The combined use of soldering method is to be avoided (However, except the pin area heating method).

For details of recommended soldering conditions for surface mounting, refer to information document SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL (C10535E).

[MEMO]

[MEMO]



ATTENTION

OBSERVE PRECAUTIONS
FOR HANDLING
ELECTROSTATIC
SENSITIVE
DEVICES

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Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

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Anti-radioactive design is not implemented in this product.

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